

**60V DUAL PNP SMALL SIGNAL TRANSISTOR IN SOT363**
**Features**

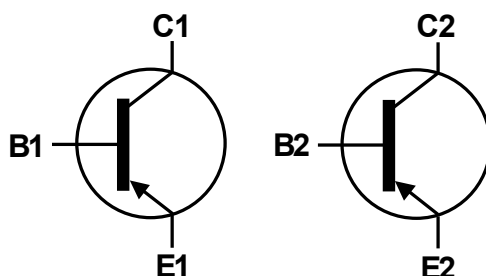
- Ultra-Small Surface Mount Package
- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

**Mechanical Data**

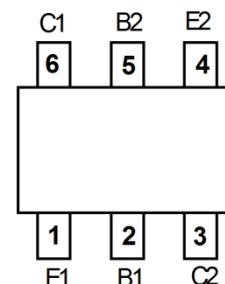
- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound.  
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — Matte Tin Finish. Solderable per MIL-STD-202, Method 208 **e3**
- Weight: 0.006 grams (approximate)



Top View



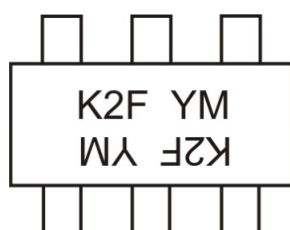
Device Symbol


 Top View  
Pin-Out

**Ordering Information** (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMDT2907A-7-F	AEC-Q101	K2F	7	8	3,000
MMDT2907AQ-7-F	Automotive	K2F	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
  5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**


K2F = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year (ex: A = 2013)  
 M = Month (ex: 9 = September)

**Date Code Key**

Year	2010	2011	2012	2013	2014	2015	2016	2017
Code	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current	I <sub>C</sub>	-600	mA

**Thermal Characteristics** (@T<sub>A</sub> = +25°C unless otherwise specified.)

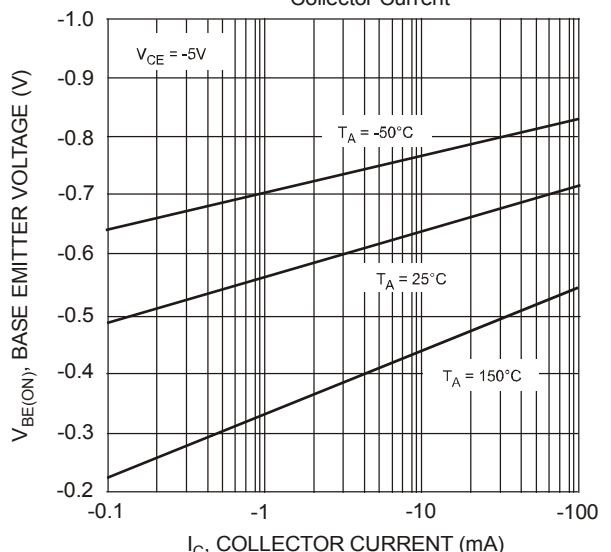
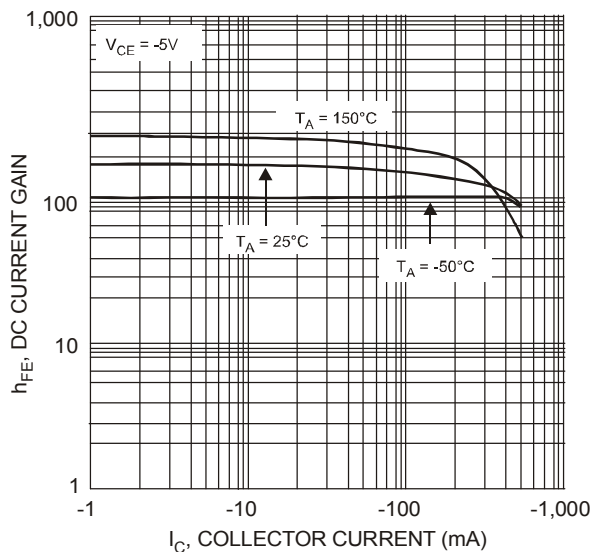
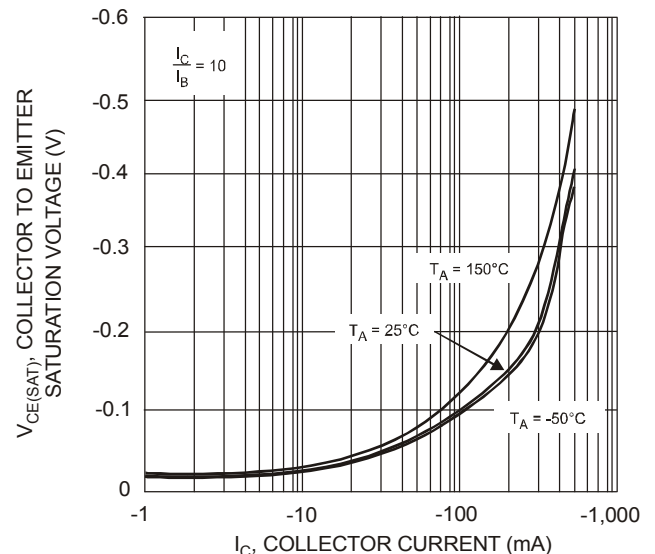
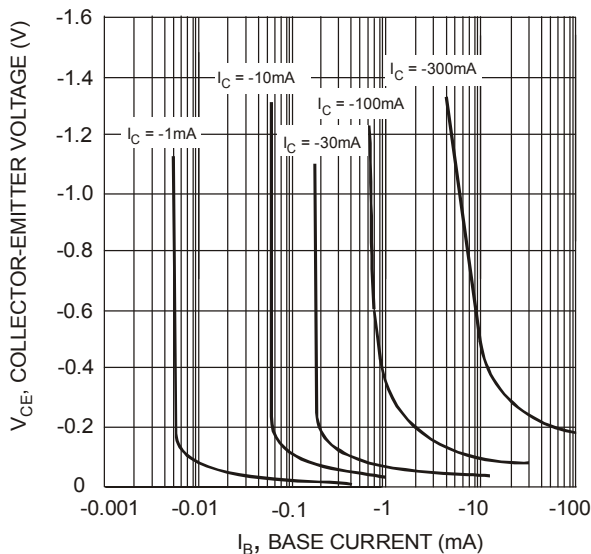
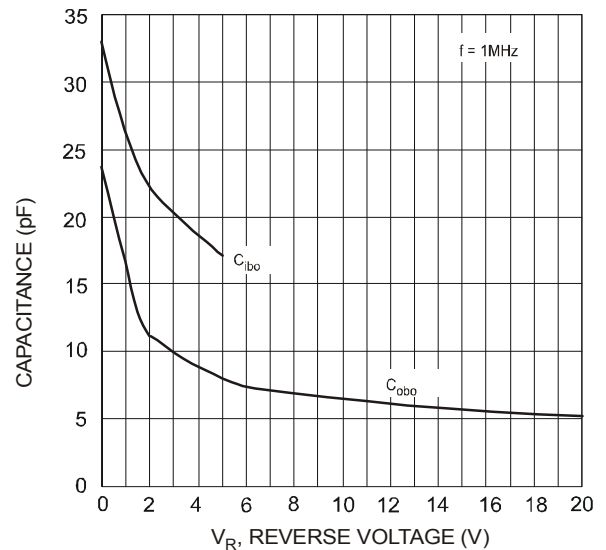
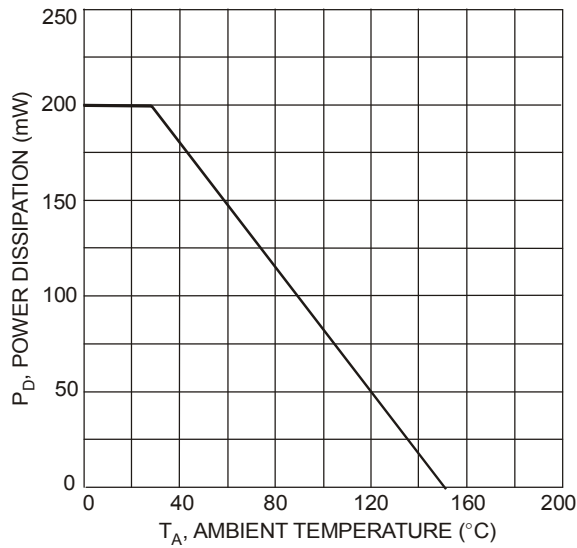
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	R <sub>θJA</sub>	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**Electrical Characteristics** (@T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-60	—	—	V	I <sub>C</sub> = -10μA, I <sub>B</sub> = 0
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	-60	—	—	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	—	—	V	I <sub>E</sub> = -10μA, I <sub>C</sub> = 0
Collector Cutoff Current	I <sub>CBO</sub>	—	—	-10	nA	V <sub>CB</sub> = -50V, I <sub>E</sub> = 0
Collector Cutoff Current	I <sub>CEX</sub>	—	—	-50	nA	V <sub>CB</sub> = -50V, I <sub>E</sub> = 0, T <sub>A</sub> = +125°C
Base Cutoff Current	I <sub>BL</sub>	—	—	-50	nA	V <sub>CE</sub> = -30V, V <sub>EB(OFF)</sub> = -0.5V
<b>ON CHARACTERISTICS (Note 7)</b>						
DC Current Gain	h <sub>FE</sub>	75	—	—	—	I <sub>C</sub> = -100μA, V <sub>CE</sub> = -10V
		100	—	—	—	I <sub>C</sub> = -1.0mA, V <sub>CE</sub> = -10V
		100	—	—	—	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -10V
		100	—	300	—	I <sub>C</sub> = -150mA, V <sub>CE</sub> = -10V
		50	—	—	—	I <sub>C</sub> = -500mA, V <sub>CE</sub> = -10V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	—	-0.4 -1.6	V	I <sub>C</sub> = -150mA, I <sub>B</sub> = -15mA I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	—	—	-1.3 -2.6	V	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Output Capacitance	C <sub>OBO</sub>	—	—	8.0	pF	V <sub>CB</sub> = -10V, f = 1.0MHz, I <sub>E</sub> = 0
Input Capacitance	C <sub>IBO</sub>	—	—	30	pF	V <sub>EB</sub> = -2.0V, f = 1.0MHz, I <sub>C</sub> = 0
Current Gain Bandwidth Product	f <sub>T</sub>	200	—	—	MHz	V <sub>CE</sub> = -20V, I <sub>C</sub> = -50mA, f = 100MHz
<b>SWITCHING CHARACTERISTICS</b>						
Turn-On Time	t <sub>off</sub>	—	—	45	ns	V <sub>CC</sub> = -30V, I <sub>C</sub> = -150 mA, I <sub>B1</sub> = -15mA
Delay Time	t <sub>d</sub>	—	—	10	ns	
Rise Time	t <sub>r</sub>	—	—	40	ns	
Turn-Off Time	t <sub>off</sub>	—	—	100	ns	V <sub>CC</sub> = -6V, I <sub>C</sub> = -150 mA, I <sub>B1</sub> = -I <sub>B2</sub> = -15mA
Storage Time	t <sub>s</sub>	—	—	80	ns	
Fall Time	t <sub>f</sub>	—	—	30	ns	

Notes: 6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.  
7. Short duration pulse test used to minimize self-heating effect.

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$  unless otherwise specified.)



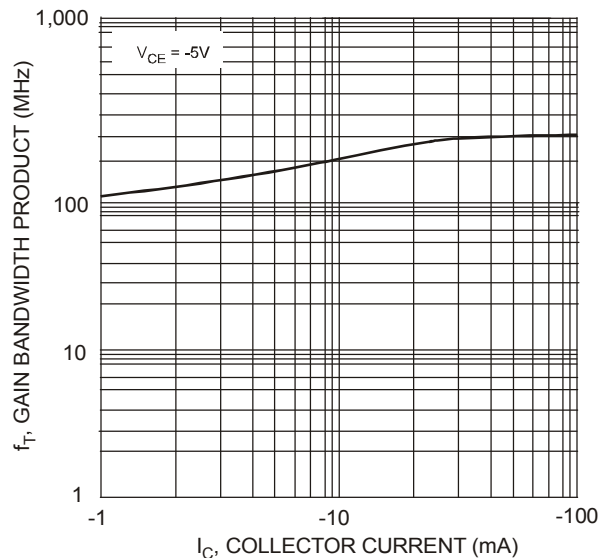
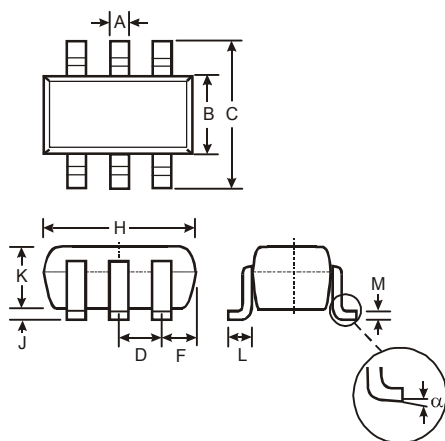


Fig. 7, Gain Bandwidth Product vs. Collector Current

## Package Outline Dimensions

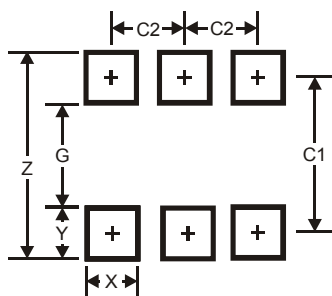
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT363			
Dim	Min	Max	Typ
A	0.10	0.30	0.25
B	1.15	1.35	1.30
C	2.00	2.20	2.10
D	0.65 Typ		
F	0.40	0.45	0.425
H	1.80	2.20	2.15
J	0	0.10	0.05
K	0.90	1.00	1.00
L	0.25	0.40	0.30
M	0.10	0.22	0.11
$\alpha$	0°	8°	-
All Dimensions in mm			

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

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### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

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